



Part Number: DxG-T RoHS Exemptions 5 & 7a

X= 1, 2, 3, 4, 5, 6, 7 Weight (mg): 130 applied

Element	Material Group	Materials	CAS (if applicable)	Average mass homogeneous Materal(%)		Mass (mg)	ppm Homogeneous Material	ppm overall
Chip	Silicon w/Metal	Doped Silicon*	7440-21-3	96.49%	0.28	0.37	964900	2846
		PbO	1317-36-8	2.43			2430000	0
		Ni	7440-02-0	1.08%			10800	0
Leadframe	Copper Alloy	Cu	7440-50-8	97.45%	73.60	95.68	974500	736000
		Fe	7439-89-6	2.40%			24000	0
		P	7723-14-0	0.03%			300	0
		Zn	7440-66-6	0.12%			1200	0
Die Attach Solder	RoHS Exempt	Lead	7439-92-1	92.50%	2.47	3.21	925000	24692
	High	Sn	7440-31-5	5.00%			50000	0
	Temperature	Silver	7440-22-4	2.50%			25000	0
Encapsulation		Silica (SiO ₂) (60~90%)	14808-60-7	75.00%	22.65	29.44	750000	226462
		formeed delived (10, 1797)	29690-82-2	13.50%			135000	0
		Phenol-formaldehyde polymer (5~10%)	9003-35-4	7.50%			75000	0
		TBBA-diglycidyl-ether oligomer (1~2%)	40039-93-8	1.50%			15000	0
		Sb ₂ O ₃ (0~5%)	1309-64-4	2.50%			25000	0
Lead Plating Finish	Matte Tin	Tin	7440-31-5	100.00%	1.00	1.30	1000000	10000
				Total	100.00	130.00		1000000

Tolerance ±10%

This data is based on information provided by our suppliers. We believe it to be correct but do not routinely validate it by measurement. It is for guidance only and Diodes Inc. does not guarantee its absolute accuracy or completeness

This product or product family does not contain any of the following substances except as CURRENTLY exempted by ELV II and RoHS and reported above: Asbestos

Azo compounds

Cadmium and cadmium compounds Certain Shortchain Chlorinated Paraffins

Chlorinated organic compounds

Hexavalent chromium compounds Lead and lead compounds

Mercury and mercury compounds

Organic tin compounds

REACH SVHCs:

Anthracene

4,4'- Diaminodiphenylmethane Dibutyl phthalate

Cyclododecane Cobalt dichloride Diarsenic pentaoxide Diarsenic trioxide

Sodium dichromate, dihydrate

Ozone Depleting Substances - Class I (CFCs, HBFCs, etc.) Ozone Depleting Substances - Class II (HCFCs)

Perfluorooctane Sulphonate (PFOS) or related compounds

Polybrominated biphenyls (PBB) and Polybrominated diphenyl ethers (PBDE) includin@ecaBDE

Polychlorinated Biphenyls (PCBs)

Polychlorinated Naphthalenes (> 3 chlorine atoms)

Radioactive Substances

Tributyl Tin (TBT) and Triphenyl Tin (TPT)

Tributyl Tin Oxide (TBTO)

5-tert-butyl-2,4,6-trinitro-m-xylene (musk xylene)

Bis (2-ethyl(hexyl)phthalate) (DEHP)

Hexabromocyclododecane (HBCDD) Alkanes, C10-13, chloro (Short Chain Chlorinated Paraffins)

Bis(tributyltin)oxide Lead hydrogen arsenate Triethyl arsenate Benzyl butyl phthalate

^{*} The Silicon Chip is doped at atomic levels with trace amounts of elements that may include Phosphorus, Boron, Arsenic, and other elements. Metalization may include Titanium, Nickel, Aluminum, Silver or Gold These substances are not reported where their concentration is less than the minimum reportable level per the guidelines specified in the Tables o EIA JIG-101, Material Composition Declaration for Electronic Products.